
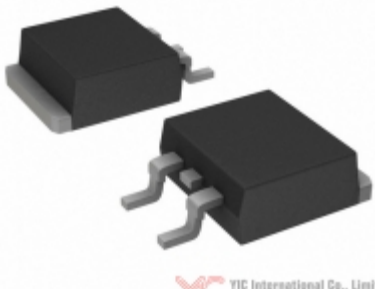
	<h2 style="color: #E67E22;">FQB16N25TM</h2> <p><b>Hersteller-Teilenummer:</b> <a href="#">FQB16N25TM</a></p> <hr/> <p><b>Hersteller / Marke:</b> <a href="#">Fairchild/ON Semiconductor</a></p> <hr/> <p><b>Teil der Beschreibung:</b> MOSFET N-CH 250V 16A D2PAK</p> <hr/> <p><b>Datenblätter:</b>  <a href="#">FQB16N25TM.pdf</a></p> <hr/> <p><b>RoHs Status:</b> Bleifrei / RoHS-konform</p> <hr/> <p><b>Lagerzustand:</b> New original, 5490 pcs Stock Available.</p> <hr/> <p><b>Liefern von:</b> Hong Kong</p> <hr/> <p><b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

### Spezifikationen

Teilenummer	FQB16N25TM
Hersteller	Fairchild/ON Semiconductor
Beschreibung	MOSFET N-CH 250V 16A D2PAK
Kategorie	<a href="#">Diskrete Halbleiterprodukte</a> > <a href="#">Transistoren-FETs</a> ,
Teilstatus	5490 pcs Stock
Serie	QFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-263-3, D <sup>2</sup> Pak (2 Leads + Tab), TO-263AB
Supplier Device-Gehäuse	D <sup>2</sup> PAK (TO-263AB)
Verlustleistung (max)	3.13W (Ta), 142W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	250V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	16A (Tc)
Rds On (Max) @ Id, Vgs	230 mOhm @ 8A, 10V
VGS (th) (Max) @ Id	5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	35nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	1200pF @ 25V
Verpackung	Tape & Reel (TR)



















































FQB16N25TM ist neu im Original, Suche FQB16N25TM Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FQB16N25TM Fairchild/ON Semiconductor mit Garantie und Vertrauen. Anfrage FQB16N25TM: [Info@Y-IC.com](mailto:Info@Y-IC.com)

Sie können auch interessiert sein:

 <p><b>FQB16N25CTM</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 250V 15.6A D2PAK</p>	 <p><b>FQB16N25CTM</b> Fairchild/ON Semiconductor MOSFET N-CH 250V 15.6A D2PAK</p>	 <p><b>FQB17N08</b> FSC FSC TO-263</p>	 <p><b>FQB16N25</b> FSC FQB16N25 FSC</p>
 <p><b>FQB17N08TM</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 80V 16.5A D2PAK</p>	 <p><b>FQB16N25TM</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 250V 16A D2PAK</p>	 <p><b>FQB17N08LTM</b> Fairchild/ON Semiconductor MOSFET N-CH 80V 16.5A D2PAK</p>	 <p><b>FQB16N15TM</b> Fairchild/ON Semiconductor MOSFET N-CH 150V 16.4A D2PAK</p>

### heiße Teile

Mehr

 FQB12N50TM_AM002	 FQB12N50TM_AM002	 FQB12N60	 FQB12N60C	 FQB12N60CTM
 FQB12N60CTM	 FQB12N60TM	 FQB12N60TM_AM002	 FQB12N60TM_AM002	 FQB12P10
 FQB12P10TM	 FQB12P10TM	 FQB12P20	 FQB12P20TM	 FQB12P20TM
 FQB13N06L	 FQB13N10	 FQB13N10L	 FQB13N50	 FQB13N50CTM
 FQB13N50CTM	 FQB140N03L	 FQB14N30TM	 FQB14N30TM	 FQB16N25TM
 FQB17P06	 FQB17P10	 FQB17P10TM	 FQB17P10TM	 FQB19N10L
 FQB19N10LTM	 FQB19N10LTM	 FQB19N10TM	 FQB19N10TM	 FQB19N20
 FQB19N20C	 FQB19N20CTM	 FQB19N20CTM	 FQB19N20L	 FQB19N20LTM
 FQB19N20LTM	 FQB19N20TM	 FQB19N20TM	 FQB1N60TM	 FQB1N60TM
 FQB20N06L	 FQB20N60FTM	 FQB20N60TM	 FQB22P10	 FQB22P10TM

Contact us: [Info@Y-IC.com](mailto:Info@Y-IC.com)

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